

54ACT11241, 74ACT11241 OCTAL BUFFERS/LINE DRIVERS WITH 3-STATE OUTPUTS

SCAS011B – D2957, JULY 1987 – REVISED APRIL 1993

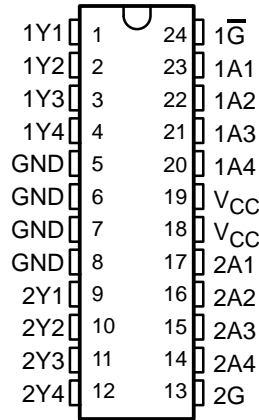
- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Inputs Are TTL-Voltage Compatible
- Flow-Through Architecture Optimizes PCB Layout
- Center-Pin V_{CC} and GND Configurations Minimize High-Speed Switching Noise
- EPIC™ (Enhanced-Performance Implanted CMOS) 1- μ m Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages, Plastic Shrink Small-Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

description

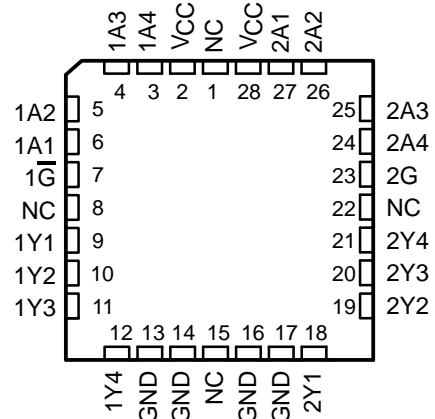
These octal buffers or line drivers are designed specifically to improve both the performance and density of three-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. Taken together with the ACT11240 and ACT11244, these devices provide the choice of selected combinations of inverting and noninverting outputs, symmetrical \overline{G} (active-low output control) inputs, and complementary G and \overline{G} inputs. These devices feature high fan-out.

The 54ACT11241 is characterized for operation over the full military temperature range of – 55°C to 125°C. The 74ACT11241 is characterized for operation from – 40°C to 85°C.

54ACT11241 . . . JT PACKAGE
74ACT11241 . . . DB, DW OR NT PACKAGE
(TOP VIEW)



54ACT11241 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection

FUNCTION TABLE

| OUTPUT CONTROL $\overline{1G}$ | DATA INPUT 1A | OUTPUT 1Y | OUTPUT CONTROL 2G | DATA INPUT 2A | OUTPUT 2Y |
|--------------------------------|---------------|-----------|-------------------|---------------|-----------|
| H | X | Z | L | X | Z |
| L | L | L | H | L | L |
| L | H | H | H | H | H |

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

TEXAS
INSTRUMENTS

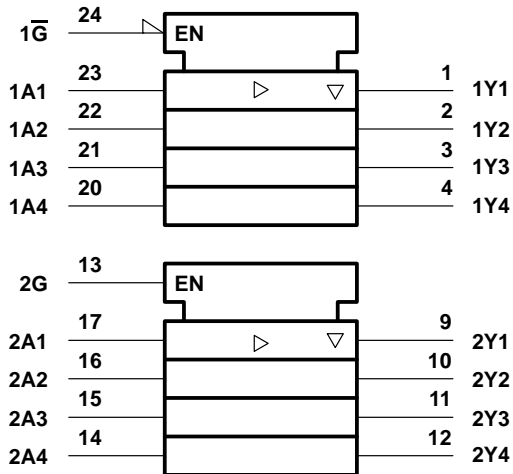
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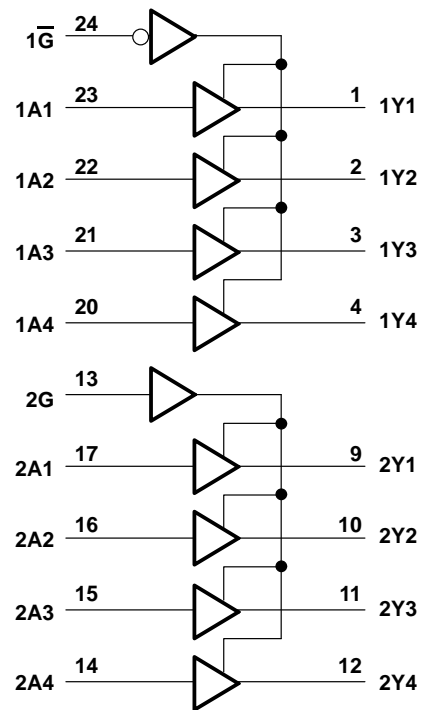
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logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



Pin numbers shown are for the DW, JT, and NT packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

| | |
|--|----------------------------|
| Supply voltage range, V_{CC} | -0.5 V to 7 V |
| Input voltage range, V_I (see Note 1) | -0.5 V to $V_{CC} + 0.5$ V |
| Output voltage range, V_O (see Note 1) | -0.5 V to $V_{CC} + 0.5$ V |
| Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$) | ± 20 mA |
| Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$) | ± 50 mA |
| Continuous output current, I_O ($V_O = 0$ to V_{CC}) | ± 50 mA |
| Continuous current through V_{CC} or GND | ± 200 mA |
| Storage temperature range | -65°C to 150°C |

‡Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at the se or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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recommended operating conditions

| | | 54ACT11241 | | 74ACT11241 | | UNIT |
|---------------------|------------------------------------|------------|----------|------------|----------|------|
| | | MIN | MAX | MIN | MAX | |
| V_{CC} | Supply voltage | 4.5 | 5.5 | 4.5 | 5.5 | V |
| V_{IH} | High-level input voltage | 2 | | 2 | | V |
| V_{IL} | Low-level input voltage | | 0.8 | | 0.8 | V |
| V_I | Input voltage | 0 | V_{CC} | 0 | V_{CC} | V |
| V_O | Output voltage | 0 | V_{CC} | 0 | V_{CC} | V |
| I_{OH} | High-level output current | | -24 | | -24 | mA |
| I_{OL} | Low-level output current | | 24 | | 24 | mA |
| $\Delta t/\Delta v$ | Input transition rise or fall rate | 0 | 10 | 0 | 10 | ns/V |
| T_A | Operating free-air temperature | -55 | 125 | -40 | 85 | °C |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | V_{CC} | $T_A = 25^\circ\text{C}$ | | | 54ACT11241 | | 74ACT11241 | | UNIT |
|-----------------------------------|--|----------|--------------------------|-----|-----------|------------|----------|------------|---------------|------|
| | | | MIN | TYP | MAX | MIN | MAX | MIN | MAX | |
| V_{OH} | $I_{OH} = -50 \mu\text{A}$ | 4.5 V | 4.4 | | | 4.4 | | 4.4 | V | |
| | | 5.5 V | 5.4 | | | 5.4 | | 5.4 | | |
| | $I_{OH} = -24 \text{ mA}$ | 4.5 V | 3.94 | | | 3.7 | | 3.8 | | |
| | | 5.5 V | 4.94 | | | 4.7 | | 4.8 | | |
| | $I_{OH} = -50 \text{ mA}^\dagger$ | 5.5 V | | | | 3.85 | | | | |
| $I_{OH} = -75 \text{ mA}^\dagger$ | 5.5 V | | | | | | 3.85 | | | |
| V_{OL} | $I_{OL} = 50 \mu\text{A}$ | 4.5 V | | | 0.1 | | 0.1 | 0.1 | V | |
| | | 5.5 V | | | 0.1 | | 0.1 | 0.1 | | |
| | $I_{OL} = 24 \text{ mA}$ | 4.5 V | | | 0.36 | | 0.5 | 0.44 | | |
| | | 5.5 V | | | 0.36 | | 0.5 | 0.44 | | |
| | $I_{OL} = 50 \text{ mA}^\dagger$ | 5.5 V | | | | | 1.65 | | | |
| $I_{OL} = 75 \text{ mA}^\dagger$ | 5.5 V | | | | | | 1.65 | | | |
| I_{OZ} | $V_O = V_{CC}$ or GND | 5.5 V | | | ± 0.5 | | ± 10 | ± 5 | μA | |
| I_I | $V_I = V_{CC}$ or GND | 5.5 V | | | ± 0.1 | | ± 1 | ± 1 | μA | |
| I_{CC} | $V_I = V_{CC}$ or GND, $I_O = 0$ | 5.5 V | | | 8 | | 160 | 80 | μA | |
| ΔI_{CC}^\ddagger | One input at 3.4 V, Other inputs at GND or V_{CC} | 5.5 V | | | 0.9 | | 1 | 1 | mA | |
| C_i | $V_I = V_{CC}$ or GND | 5 V | | | 4 | | | | pF | |
| C_o | $V_O = V_{CC}$ or GND | 5 V | | | 10 | | | | pF | |

† Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

‡ This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V_{CC} .

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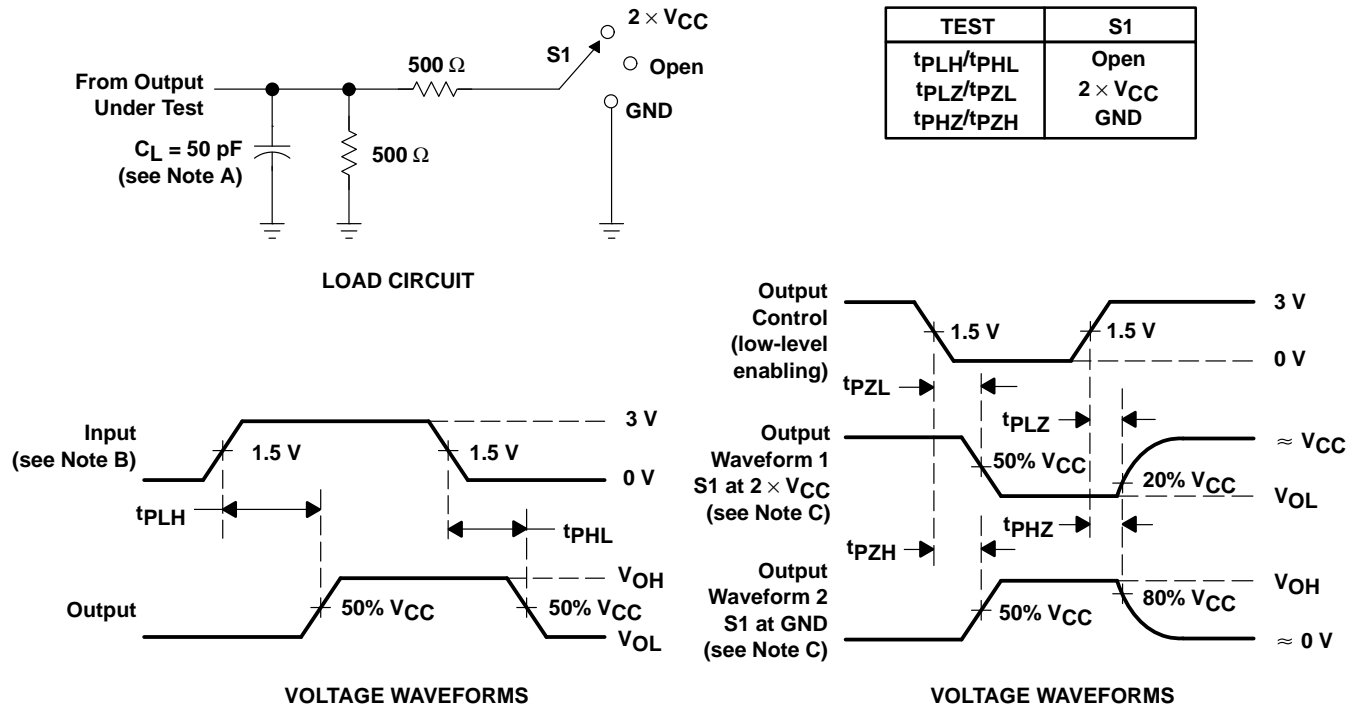
switching characteristics over recommended operating free-air temperature range,
 $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $T_A = 25^\circ\text{C}$ | | | 54ACT11241 | | 74ACT11241 | | UNIT |
|-----------|----------------|-------------|--------------------------|-----|------|------------|------|------------|------|------|
| | | | MIN | TYP | MAX | MIN | MAX | MIN | MAX | |
| t_{PLH} | A | Y | 1.5 | 6.6 | 9 | 1.5 | 10.7 | 1.5 | 10 | ns |
| t_{PHL} | | | 1.5 | 6.3 | 8.5 | 1.5 | 9.5 | 1.5 | 9.1 | |
| t_{PZH} | G or \bar{G} | Y | 1.5 | 7.5 | 11.3 | 1.5 | 13 | 1.5 | 12.3 | |
| t_{PZL} | | | 1.5 | 7.4 | 10.5 | 1.5 | 11.9 | 1.5 | 11.3 | |
| t_{PHZ} | G or \bar{G} | Y | 1.5 | 7.6 | 10.6 | 1.5 | 11.4 | 1.5 | 11 | |
| t_{PLZ} | | | 1.5 | 8.2 | 11.2 | 1.5 | 12 | 1.5 | 11.7 | |

operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

| PARAMETER | | TEST CONDITIONS | TYP | UNIT |
|-----------|--|---|-----|------|
| C_{pd} | Power dissipation capacitance per buffer | $C_L = 50\text{ pF}$, $f = 1\text{ MHz}$ | 27 | pF |
| | | | 9 | |

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
 B. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r = 3\text{ ns}$, $t_f = 3\text{ ns}$.
 C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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